

REMARKS

Reference to the parent application has been added and the title has been amended. New claims to the structure of the embedded DRAM capacitor structure have been added. No new matter has been added.

All Claims are believed to be Allowable.

It is requested that should the Examiner not find that the Claims are now Allowable that the Examiner call the undersigned at 765 453-0866 to overcome any problems preventing allowance.

Respectfully submitted,

Stephen B. Ackerman, Reg. No. 37,761

**PLEASE AMEND THE SPECIFICATION AS FOLLOWS:**

After the title, insert -- This is a continuation of Patent Application serial number 10/411,347, filing date 4/10/03, Method Of Fabricating An Embedded DRAM For Metal-Insulator-Metal (MIM) Capacitor Structure, assigned to the same assignee as the present invention, which is herein incorporated by reference in its entirety.

**REMARKS**

A reference to the parent case has been added by Preliminary Amendment to this Continuation.

The application is believed to be in condition for allowance. Allowance of the subject Patent Application is therefore respectfully requested.

Respectfully submitted,

A handwritten signature in black ink, appearing to read 'S.B. Ackerman', with a stylized flourish at the end.

STEPHEN B. ACKERMAN, REG. NO. 37,761